1 Features
- Input Voltage Range: 1.8 V to 5.5 V, 1.6 V after Startup
- Output Voltage Up to 28 V
- Integrated Power Diode and Isolation Switch
- 900-mA (typical) Switch Current
- Up to 85% Efficiency at 3.6-V Input and 12-V Output
- 500-nA Ultra-low Shutdown Current
- ±2% Output Voltage Accuracy
- Power Save Operation Mode at Light Load
- Internal 10-ms Soft Start Time
- True Disconnection between Input and Output during Shutdown
- Output Short Circuit Protection
- Output Over-Voltage Protection
- Thermal Shutdown Protection
- 0.80-mm x 1.20-mm WCSP package

2 Applications
- PMOLED Power Supply
- Wearable Devices
- Portable Medical Equipment
- Sensor Power Supply

3 Description
The TPS61046 is a highly integrated boost converter designed for applications requiring high voltage and tiny solution size such as PMOLED panel and sensor module. The TPS61046 integrates a 30-V power switch, input/output isolation switch, and power diode. It can output up to 28 V from input of a Li+ battery or two cell alkaline batteries in series.

The TPS61046 operates with a switching frequency at 1.0 MHz. This allows the use of small external components. The TPS61046 has an internal default 12-V output voltage setting by connecting the FB pin to the VIN pin. Thus it only needs three external components to get 12-V output voltage. Together with WCSP package, the TPS61046 gives a very small overall solution size. The TPS61046 has typical 900-mA switch current limit. It has 10-ms built-in soft start time to minimize the inrush current. When the TPS61046 is in shutdown mode, the isolation switch disconnects the output from input to minimize the leakage current. The TPS61064 also implements output short circuit protection, output over-voltage protection and thermal shutdown.

The TPS61046 is available in a 6-pin 0.80-mm x 1.20-mm WCSP package.

4 Simplified Schematic
# Table of Contents

1 Features .................................................................. 1
2 Applications ........................................................... 1
3 Description ................................................................ 1
4 Simplified Schematic .................................................. 1
5 Revision History ....................................................... 2
6 Pin Configuration and Functions .................................. 3
7 Specifications ............................................................. 4
   7.1 Absolute Maximum Ratings ...................................... 4
   7.2 ESD Ratings .......................................................... 4
   7.3 Recommended Operating Conditions ....................... 4
   7.4 Thermal Information .............................................. 4
   7.5 Electrical Characteristics ....................................... 5
   7.6 Typical Characteristics .......................................... 6
8 Detailed Description ................................................... 8
   8.1 Overview ............................................................... 8
   8.2 Functional Block Diagram ....................................... 8
8.3 Feature Description .................................................. 9
9 Application and Implementation .................................... 11
   9.1 Application Information .......................................... 11
   9.2 Typical Application - 12-V Output Boost Converter .... 11
   9.3 System Examples .................................................. 15
10 Power Supply Recommendations ................................. 16
11 Layout ..................................................................... 17
   11.1 Layout Guidelines ................................................ 17
   11.2 Layout Example ................................................... 17
12 Device and Documentation Support ............................... 18
   12.1 Device Support .................................................... 18
   12.2 Community Resources .......................................... 18
   12.3 Trademarks ......................................................... 18
   12.4 Electrostatic Discharge Caution ............................. 18
   12.5 Glossary ............................................................. 18
13 Mechanical, Packaging, and Orderable Information ....... 19

## Revision History

<table>
<thead>
<tr>
<th>DATE</th>
<th>REVISION</th>
<th>NOTES</th>
</tr>
</thead>
<tbody>
<tr>
<td>April 2015</td>
<td>*</td>
<td>Initial release.</td>
</tr>
</tbody>
</table>
## 6 Pin Configuration and Functions

![YFF Package 6-Ball WCSP (Top View)](image)

### Pin Functions

<table>
<thead>
<tr>
<th>PIN</th>
<th>I/O</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>EN</td>
<td>C1</td>
<td>Enable logic input. Logic high voltage enables the device. Logic low voltage disables the device and turns it into shutdown mode.</td>
</tr>
<tr>
<td>FB</td>
<td>B1</td>
<td>Voltage feedback of adjustable output voltage. Connect to the center tap of a resistor divider to program the output voltage. When it is connected to the VIN pin, the output voltage is set to 12 V by an internal feedback.</td>
</tr>
<tr>
<td>GND</td>
<td>A2</td>
<td>Ground</td>
</tr>
<tr>
<td>SW</td>
<td>B2</td>
<td>The switch pin of the converter. It is connected to the drain of the internal power MOSFET.</td>
</tr>
<tr>
<td>VIN</td>
<td>A1</td>
<td>IC power supply input</td>
</tr>
<tr>
<td>VOUT</td>
<td>C2</td>
<td>Output of the boost converter</td>
</tr>
</tbody>
</table>
7 Specifications

7.1 Absolute Maximum Ratings
over operating free-air temperature range (unless otherwise noted) (1)

<table>
<thead>
<tr>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>VIN, EN, FB</td>
<td>–0.3</td>
<td>6</td>
</tr>
<tr>
<td>SW, VOUT</td>
<td>–0.3</td>
<td>32</td>
</tr>
<tr>
<td>Operating junction temperature range, T_J</td>
<td>–40</td>
<td>150</td>
</tr>
<tr>
<td>Storage temperature range, T_stg</td>
<td>–65</td>
<td>150</td>
</tr>
</tbody>
</table>

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

7.2 ESD Ratings

<table>
<thead>
<tr>
<th>V_{(ESD)} (1)</th>
<th>Electrostatic discharge</th>
<th>VALUE</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (2)</td>
<td>±2000</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (3)</td>
<td>±500</td>
<td>V</td>
<td></td>
</tr>
</tbody>
</table>

(1) Electrostatic discharge (ESD) to measure device sensitivity and immunity to damage caused by assembly line electrostatic discharges in to the device.

(2) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(3) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions
over operating free-air temperature range (unless otherwise noted)

<table>
<thead>
<tr>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_IN</td>
<td>Input voltage range</td>
<td>1.8</td>
<td>5.5</td>
</tr>
<tr>
<td>V_OUT</td>
<td>Output voltage range</td>
<td>4.5</td>
<td>28</td>
</tr>
<tr>
<td>L</td>
<td>Effective inductance range</td>
<td>1.0×0.7</td>
<td>10×22×1.3</td>
</tr>
<tr>
<td>C_IN</td>
<td>Effective input capacitance range</td>
<td>0.22</td>
<td>1.0</td>
</tr>
<tr>
<td>C_OUT</td>
<td>Effective output capacitance range</td>
<td>0.22</td>
<td>1.0</td>
</tr>
<tr>
<td>T_J</td>
<td>Operating junction temperature</td>
<td>–40</td>
<td>125</td>
</tr>
</tbody>
</table>

7.4 Thermal Information

<table>
<thead>
<tr>
<th>THERMAL METRIC (1)</th>
<th>TPS61046</th>
</tr>
</thead>
<tbody>
<tr>
<td>YFF (WCSP)</td>
<td>135.4</td>
</tr>
<tr>
<td>6 BALLS</td>
<td>1.6</td>
</tr>
<tr>
<td>22.3</td>
<td></td>
</tr>
<tr>
<td>5.6</td>
<td></td>
</tr>
<tr>
<td>22.3</td>
<td></td>
</tr>
<tr>
<td>n/a</td>
<td></td>
</tr>
</tbody>
</table>

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
### 7.5 Electrical Characteristics

$T_J = -40°C$ to $125°C$, $V_{IN} = 3.6$ V and $V_{OUT} = 12$ V. Typical values are at $T_J = 25°C$, unless otherwise noted.

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>POWER SUPPLY</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$V_{IN}$</td>
<td>Input voltage range</td>
<td>1.8</td>
<td>5.5</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN,UVLO}$</td>
<td>Under voltage lockout threshold</td>
<td>1.75</td>
<td>1.8</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN,UVLO}$</td>
<td>Under voltage lockout threshold</td>
<td>1.55</td>
<td>1.6</td>
<td>mV</td>
<td></td>
</tr>
<tr>
<td>$V_{IN,UHYS}$</td>
<td>VIN UVLO hysteresis</td>
<td>200</td>
<td></td>
<td></td>
<td>mV</td>
</tr>
<tr>
<td>$I_{O,VIN}$</td>
<td>Quiescent current into VIN pin</td>
<td>110</td>
<td>200</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>$I_{SD}$</td>
<td>Shutdown current into VIN pin</td>
<td>0.1</td>
<td>0.8</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td></td>
<td>IC disabled, $V_{IN} = 1.8$ V to 5.5 V, $T_J$ up to 85°C</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>IC disabled, $V_{IN} = 1.8$ V to 5.5 V, $T_J$ up to 60°C</td>
<td>0.5</td>
<td></td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td><strong>OUTPUT</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$V_{OUT}$</td>
<td>Output voltage range</td>
<td>4.5</td>
<td>28</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{OUT,12V}$</td>
<td>12-V output voltage accuracy</td>
<td>11.7</td>
<td>12</td>
<td>12.3</td>
<td>V</td>
</tr>
<tr>
<td>$V_{REF}$</td>
<td>Feedback voltage</td>
<td>0.779</td>
<td>0.795</td>
<td>0.811</td>
<td>V</td>
</tr>
<tr>
<td>$V_{OVP}$</td>
<td>Output overvoltage protection threshold</td>
<td>28</td>
<td>29.2</td>
<td>30.4</td>
<td>V</td>
</tr>
<tr>
<td>$V_{OVP,HYS}$</td>
<td>Over voltage protection hysteresis</td>
<td>0.8</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>$I_{FB,LKG}$</td>
<td>Leakage current into FB pin</td>
<td>200</td>
<td></td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td>$I_{SW,LKG}$</td>
<td>Leakage current into SW pin</td>
<td>500</td>
<td></td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td><strong>POWER SWITCH</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$R_{DS(on)}$</td>
<td>Isolation MOSFET on resistance</td>
<td>850</td>
<td></td>
<td></td>
<td>mΩ</td>
</tr>
<tr>
<td>$R_{DS(on)}$</td>
<td>Low-side MOSFET on resistance</td>
<td>450</td>
<td></td>
<td></td>
<td>mΩ</td>
</tr>
<tr>
<td>$f_{SW}$</td>
<td>Switching frequency</td>
<td>850</td>
<td>1050</td>
<td>1250</td>
<td>kHz</td>
</tr>
<tr>
<td>$t_{ON}$</td>
<td>Minimal switch on time</td>
<td>150</td>
<td>250</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>$I_{SW}$</td>
<td>Peak switch current limit</td>
<td>600</td>
<td>900</td>
<td>1200</td>
<td>mA</td>
</tr>
<tr>
<td>$I_{CHG}$</td>
<td>Pre-charge current</td>
<td>30</td>
<td>50</td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>$t_{STARTUP}$</td>
<td>Startup time</td>
<td>2</td>
<td>5</td>
<td></td>
<td>ms</td>
</tr>
<tr>
<td><strong>LOGIC INTERFACE</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$V_{EN,H}$</td>
<td>EN Logic high threshold</td>
<td>1</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>$V_{EN,L}$</td>
<td>EN Logic Low threshold</td>
<td>0.4</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td><strong>PROTECTION</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$T_{SD}$</td>
<td>Thermal shutdown threshold</td>
<td>150</td>
<td></td>
<td></td>
<td>°C</td>
</tr>
<tr>
<td>$T_{SD,HYS}$</td>
<td>Thermal shutdown hysteresis</td>
<td>20</td>
<td></td>
<td></td>
<td>°C</td>
</tr>
</tbody>
</table>
7.6 Typical Characteristics

\( V_{IN} = 3.6 \, V, \, V_{OUT} = 12 \, V, \, T_{J} = -40^\circ C \text{ to } 125^\circ C, \) unless otherwise noted.

---

**Figure 1. Efficiency vs Output Current**

\( V_{IN} = 1.8 \, V, 3.0 \, V, 3.6 \, V, 4.2 \, V, \, V_{OUT} = 12 \, V \)

**Figure 2. Efficiency vs Output Current**

\( V_{IN} = 3.6 \, V, \, V_{OUT} = 5 \, V, 12 \, V, 24 \, V \)

---

**Figure 3. 12-V Fixed Output Voltage vs Temperature**

\( V_{IN} = 3.6 \, V, \, V_{OUT} = 12 \, V, \, \text{FB pin connected to VIN pin} \)

**Figure 4. Reference Voltage vs Temperature**

\( V_{IN} = 3.6 \, V, \, V_{OUT} = 12 \, V \)

---

**Figure 5. Quiescent Current vs Temperature**

\( V_{IN} = 3.6 \, V, \, V_{OUT} = 12 \, V, \, \text{No switching} \)

**Figure 6. Quiescent Current vs Input Voltage**

\( V_{IN} = 1.8 \, V \text{ to } 6 \, V, \, V_{OUT} = 12 \, V, \, \text{No switching} \)
Typical Characteristics (continued)

\( V_{IN} = 3.6 \text{ V}, V_{OUT} = 12 \text{ V}, T_J = -40^\circ \text{C} \text{ to } 125^\circ \text{C}, \) unless otherwise noted.

**Figure 7. Shutdown Current vs Temperature**

\( V_{IN} = 3.6 \text{ V} \)

**Figure 8. Current Limit vs Temperature**

\( V_{IN} = 3.6 \text{ V}, V_{OUT} = 12 \text{ V} \)

**Figure 9. Current Limit vs Temperature**

\( V_{IN} = 1.8 \text{ V} \text{ to } 6 \text{ V}, V_{OUT} = 12 \text{ V} \)
8 Detailed Description

8.1 Overview

The TPS61046 is a highly integrated boost converter designed for applications requiring high voltage and tiny solution size such as PMOLED panel power supply and sensor module. The TPS61046 integrates a 30-V power switch, input/output isolation switch, and power diode. It can output up to 28 V from input of a Li+ battery or two cell alkaline batteries in series.

One common issue with conventional boost regulators is the conduction path from input to output even when the power switch is turned off. It creates three problems, which are inrush current during start-up, output leakage current during shutdown and excessive over load current. In the TPS61046, the isolation switch is turned off under shutdown mode and over load conditions, thereby opening the current path. Thus the TPS61046 can truly disconnect the load from the input voltage and minimize the leakage current during shutdown mode.

The TPS61046 operates with a switching frequency at 1.0 MHz. This allows the use of small external components. The TPS61046 has an internal default 12-V output voltage setting by connecting the FB pin to the VIN pin. Thus it only needs three external components to get 12-V output voltage. Together with WCSP package, the TPS61046 gives a very small overall solution size. The TPS61046 has typical 900-mA switch current limit. It has 10-ms built-in soft start time to minimize the inrush current. The TPS61064 also implements output short circuit protection, output over-voltage protection and thermal shutdown.

8.2 Functional Block Diagram
8.3 Feature Description

8.3.1 Under-Voltage Lockout
An under-voltage lockout (UVLO) circuit stops the operation of the converter when the input voltage drops below the typical UVLO threshold of 1.55 V. A hysteresis of 200 mV is added so that the device cannot be enabled again until the input voltage goes up to 1.75 V. This function is implemented in order to prevent malfunctioning of the device when the input voltage is between 1.55 V and 1.75 V.

8.3.2 Enable and Disable
When the input voltage is above maximal UVLO rising threshold of 1.8 V and the EN pin is pulled high, the TPS61046 is enabled. When the EN pin is pulled low, the TPS61046 goes into shutdown mode. The device stops switching and the isolation switch is turned off providing the isolation between input and output. In shutdown mode, less than 1-µA input current is consumed.

8.3.3 Soft Start
The TPS61046 begins soft start when the EN pin is pulled high. at the beginning of the soft start period, the isolation FET is turned on slowly to charge the output capacitor with 30-mA current for about 5 ms. This is called the pre-charge phase. After the pre-charge phase, the TPS61046 starts switching. This is called switching soft start phase. An internal soft start circuit limits the peak inductor current according to the output voltage. When the output voltage is below 3 V, the peak inductor current is limited to 140 mA. Along with the output voltage going up from 3 V to 5 V, the peak current limit is gradually increased to the normal value of 900 mA. The switching soft start phase is about 5 ms typically. The soft start function reduces the inrush current during startup.

8.3.4 Over-voltage Protection
The TPS61046 has internal output over-voltage protection (OVP) function. When the output voltage exceeds the OVP threshold of 29.2 V, the device stops switching. Once the output voltage falls 0.8 V below the OVP threshold, the device resumes operation again.

8.3.5 Output Short Circuit Protection
The TPS61046 starts to limit the output current whenever the output voltage drops below 4 V. The lower output voltage, the smaller output current limit. When the VOUT pin is shorted to ground, the output current is limited to less than 200 mA. This function protects the device from being damaged when the output is shorted to ground.

8.3.6 Thermal Shutdown
The TPS61046 goes into thermal shutdown once the junction temperature exceeds 150°C. When the junction temperature drops below the thermal shutdown temperature threshold less the hysteresis, typically 130°C, the device starts operating again.

8.3.7 Device Functional Modes
The TPS61046 has two operation modes, PWM mode and power save mode.

8.3.7.1 PWM Mode
The TPS61046 uses a quasi-constant 1.0-MHz frequency pulse width modulation (PWM) at moderate to heavy load current. Based on the input voltage to output voltage ratio, a circuit predicts the required off-time. At the beginning of the switching cycle, the NMOS switching FET, shown in the functional block diagram, is turned on. The input voltage is applied across the inductor and the inductor current ramps up. In this phase, the output capacitor is discharged by the load current. When the inductor current hits the current threshold that is set by the output of the error amplifier, the PWM switch is turned off, and the power diode is forward-biased. The inductor transfers its stored energy to replenish the output capacitor and supply the load. When the off-time is expired, the next switching cycle starts again. The error amplifier compares the FB pin voltage with an internal reference voltage, and its output determines the inductor peak current.

The TPS61046 has a built-in compensation circuit that can accommodate a wide range of input voltage, output voltage, inductor value and output capacitor value for stable operation.
Feature Description (continued)

8.3.8 Power Save Mode

The TPS61046 integrates a power save mode with pulse frequency modulation (PFM) to improve efficiency at light load. When the load current decreases, the inductor peak current set by the output of the error amplifier declines to regulate the output voltage. When the inductor peak current hits the low limit of 140 mA, the output voltage will exceed the setting voltage as the load current decreases further. When the FB voltage hits the PFM reference voltage, the TPS61046 goes into the power save mode. In the power save mode, when the FB voltage rises and hits the PFM reference voltage, the device continuous switching for several cycles because of the delay time of the internal comparator. Then it stops switching. The load is supplied by the output capacitor and the output voltage declines. When the FB voltage falls below the PFM reference voltage, after the delay time of the comparator, the device starts switching again to ramp up the output voltage.

![Figure 10. Output Voltage in PWM Mode and PFM Mode](image-url)
9 Application and Implementation

9.1 Application Information
The TPS61046 is a boost DC-DC converter with a PWM switch, a power diode and an input/output isolation switch integrated. The device supports up to 28-V output with the input range from 1.8 V to 5.5 V. The TPS61046 adopts the current-mode control with adaptive constant off-time. The switching frequency is quasi-constant at 1.0 MHz. The isolation switch disconnects the output from the input during shutdown to minimize leakage current.

The following design procedure can be used to select component values for the TPS61046.

9.2 Typical Application - 12-V Output Boost Converter

![Diagram of 12-V Boost Converter]

Figure 11. 12-V Boost Converter

9.2.1 Design Requirements

Table 1. Design Requirements

<table>
<thead>
<tr>
<th>PARAMETERS</th>
<th>VALUES</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input Voltage</td>
<td>2.7 V ~ 4.2 V</td>
</tr>
<tr>
<td>Output Voltage</td>
<td>12 V</td>
</tr>
<tr>
<td>Output Current</td>
<td>50 mA</td>
</tr>
<tr>
<td>Output Voltage Ripple</td>
<td>±50mV</td>
</tr>
</tbody>
</table>

9.2.2 Detailed Design Procedure

9.2.2.1 Programming the Output Voltage

There are two ways to set the output voltage of the TPS61046. When the FB pin is connected to the input voltage, the output voltage is fixed to 12 V. This function makes the TPS61046 only need three external components to minimize the solution size. The second way is to use an external resistor divider to set the desired output voltage.

By selecting the external resistor divider R1 and R2, as shown in Equation 1, the output voltage is programmed to the desired value. When the output voltage is regulated, the typical voltage at the FB pin is \( V_{\text{REF}} \) of 795 mV.

\[
R_1 = \left( \frac{V_{\text{OUT}}}{V_{\text{REF}}} - 1 \right) \times R_2
\]  

(1)
Where:
- \( V_{\text{OUT}} \) is the desired output voltage
- \( V_{\text{REF}} \) is the internal reference voltage at the FB pin

For best accuracy, \( R2 \) should be kept smaller than 80 k\( \Omega \) to ensure the current flowing through \( R2 \) is at least 100 times larger than the FB pin leakage current. Changing \( R2 \) towards a lower value increases the immunity against noise injection. Changing the \( R2 \) towards a higher value reduces the quiescent current for achieving highest efficiency at low load currents.

### 9.2.2.2 Inductor Selection

Because the selection of the inductor affects steady state operation, transient behavior, and loop stability, the inductor is the most important component in power regulator design. There are three important inductor specifications, inductor value, saturation current, and dc resistance (DCR).

The TPS61046 is designed to work with inductor values between 1.0 \( \mu \text{H} \) and 22 \( \mu \text{H} \). Follow Equation 2 to Equation 4 to calculate the inductor’s peak current for the application. To calculate the current in the worst case, use the minimum input voltage, maximum output voltage, and maximum load current of the application. To have enough design margin, choose the inductor value with -30% tolerance, and a low power-conversion efficiency for the calculation.

In a boost regulator, the inductor dc current can be calculated with Equation 2.

\[
I_{\text{(DC)}} = \frac{V_{\text{OUT}} \times I_{\text{OUT}}}{V_{\text{IN}} \times \eta}
\]

(2)

Where:
- \( V_{\text{OUT}} \) = output voltage
- \( I_{\text{OUT}} \) = output current
- \( V_{\text{IN}} \) = input voltage
- \( \eta \) = power conversion efficiency, use 80% for most applications

The inductor ripple current is calculated with the Equation 3 for an asynchronous boost converter in continuous conduction mode (CCM).

\[
\Delta I_{\text{(P-P)}} = \frac{V_{\text{IN}} \times (V_{\text{OUT}} + 0.8V - V_{\text{IN}})}{L \times f_{\text{SW}} \times (V_{\text{OUT}} + 0.8V)}
\]

(3)

Where:
- \( \Delta I_{\text{(P-P)}} \) = inductor ripple current
- \( L \) = inductor value
- \( f_{\text{SW}} \) = switching frequency
- \( V_{\text{OUT}} \) = output voltage
- \( V_{\text{IN}} \) = input voltage

Therefore, the inductor peak current is calculated with Equation 4.

\[
I_{\text{L(P)}} = I_{\text{(DC)}} + \frac{\Delta I_{\text{(P-P)}}}{2}
\]

(4)

Normally, it is advisable to work with an inductor peak-to-peak current of less than 40% of the average inductor current for maximum output current. A smaller ripple from a larger valued inductor reduces the magnetic hysteresis losses in the inductor and EMI. Bit in the same way, load transient response time is increased. Because the TPS61046 is for relatively small output current application, the inductor peak-to-peak current could be as high as 200% of the average current with a small inductor value, which means the TPS61046 always works in DCM mode. Table 2 lists the recommended inductor for the TPS61046.

### Table 2. Recommended Inductors for the TPS61046

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>L(( \mu \text{H} ))</th>
<th>DCR MAX (m( \Omega ))</th>
<th>SATURATION CURRENT (A)</th>
<th>SIZE (LxWxH)</th>
<th>VENDOR</th>
</tr>
</thead>
<tbody>
<tr>
<td>FDSD0420-H-100M</td>
<td>10</td>
<td>200</td>
<td>2.5</td>
<td>4.2x4.2x2.0</td>
<td>Toko</td>
</tr>
<tr>
<td>CDRH3D23/HP</td>
<td>10</td>
<td>198</td>
<td>1.02</td>
<td>4.0x4.0x2.5</td>
<td>Sumida</td>
</tr>
</tbody>
</table>
### 9.2.2.3 Input and Output Capacitor Selection

The output capacitor is mainly selected to meet the requirements for output ripple and loop stability. This ripple voltage is related to the capacitor’s capacitance and its equivalent series resistance (ESR). Assuming a ceramic capacitor with zero ESR, the minimum capacitance needed for a given ripple can be calculated by:

\[
C_{\text{OUT}} = \frac{I_{\text{OUT}} \times D_{\text{MAX}}}{f_{\text{SW}} \times V_{\text{RIPPLE}}}
\]

Where:
- \(D_{\text{MAX}}\) = maximum switching duty cycle
- \(V_{\text{RIPPLE}}\) = peak to peak output voltage ripple

The ESR impact on the output ripple must be considered if tantalum or aluminum electrolytic capacitors are used.

Care must be taken when evaluating a ceramic capacitor’s derating under dc bias, aging, and ac signal. For example, the dc bias can significantly reduce capacitance. A ceramic capacitor can lose more than 50% of its capacitance at its rated voltage. Therefore, always leave margin on the voltage rating to ensure adequate capacitance at the required output voltage.

It is recommended to use the output capacitor with effective capacitance in the range of 0.47 \(\mu\)F to 10 \(\mu\)F. The output capacitor affects the small signal control loop stability of the boost regulator. If the output capacitor is below the range, the boost regulator can potentially become unstable. Increasing the output capacitor makes the output voltage ripple smaller in PWM mode.

For input capacitor, a ceramic capacitor with more than 1.0 \(\mu\)F is enough for most applications.
9.2.3 Application Performance Curves

**Figure 12. Switching Waveforms in PWM CCM Mode**

- $V_{IN} = 3.6\, V$, $V_{OUT} = 12\, V$, $I_{OUT} = 50\, mA$

**Figure 13. Switching Waveforms in PWM DCM Mode**

- $V_{IN} = 3.6\, V$, $V_{OUT} = 12\, V$, $I_{OUT} = 20\, mA$

**Figure 14. Switching Waveforms in Power Save Mode**

- $V_{IN} = 3.6\, V$, $V_{OUT} = 12\, V$, $I_{OUT} = 3\, mA$

**Figure 15. Soft Startup**

- $V_{IN} = 3.6\, V$, $V_{OUT} = 12\, V$, $I_{OUT} = 50\, mA$

**Figure 16. Shutdown Waveforms**

- $V_{IN} = 3.6\, V$, $V_{OUT} = 12\, V$, $I_{OUT} = 50\, mA$

**Figure 17. 10-mA to 50-mA Load Transient Response**

- $V_{IN} = 3.6\, V$, $V_{OUT} = 12\, V$
9.3 System Examples

9.3.1 Fixed 12-V Output Voltage with Three External Components

The TPS61046 can output fixed 12-V voltage by connecting the FB pin to the VIN pin to save the external resistor divider. The Figure 19 shows the application circuit.

![Application Circuit Diagram](image)

Figure 19. Fixed 12-V Output Voltage by Connecting the FB Pin to VIN Pin
10 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 1.8 V to 5.5 V. This input supply must be well regulated. If the input supply is located more than a few inches from the converter, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. A typical choice is an electrolytic or tantalum capacitor with a value of 47 µF. The input power supply’s output current needs to be rated according to the supply voltage, output voltage and output current of the TPS61046.
11 Layout

11.1 Layout Guidelines

As for all switching power supplies, especially those running at high switching frequency and high currents, layout is an important design step. If the layout is not carefully done, the regulator could suffer from instability and noise problems. To maximize efficiency, switch rise and fall time are very fast. To prevent radiation of high frequency noise (for example, EMI), proper layout of the high-frequency switching path is essential. Minimize the length and area of all traces connected to the SW pin, and always use a ground plane under the switching regulator to minimize interplane coupling. The input capacitor needs not only to be close to the VIN pin, but also to the GND pin in order to reduce input supply ripple.

The most critical current path for all boost converters is from the switching FET, through the rectifier diode, then the output capacitors, and back to ground of the switching FET. This high current path contains nanosecond rise and fall time and should be kept as short as possible. Therefore, the output capacitor needs not only to be close to the VOUT pin, but also to the GND pin to reduce the overshoot at the SW pin and VOUT pin.

11.2 Layout Example

A large ground plane on the bottom layer connects the ground pins of the components on the top layer through vias.

Figure 20. PCB Layout Example
12 Device and Documentation Support

12.1 Device Support

12.1.1 Third-Party Products Disclaimer
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contact information for technical support.

12.3 Trademarks
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12.4 Electrostatic Discharge Caution
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam
during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary
SLYZ022 — Ti Glossary.
This glossary lists and explains terms, acronyms, and definitions.
13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Package summary

Chip scale package dimensions

The TPS61046 is available in a 6-bump chip scale package (YFF, NanoFree™). The package dimensions are given as:

D=ca. 1192 ± 30μm
E=ca. 792 ± 30μm
## PACKAGING INFORMATION

<table>
<thead>
<tr>
<th>Orderable Device</th>
<th>Status (1)</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan (2)</th>
<th>Lead/Ball Finish (6)</th>
<th>MSL Peak Temp (3)</th>
<th>Op Temp (°C)</th>
<th>Device Marking (4/5)</th>
<th>Samples</th>
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<td>TPS61046YFFR</td>
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<td>DSBGA</td>
<td>YFF</td>
<td>6</td>
<td>3000</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>SNAGCU</td>
<td>Level-1-260C-UNLIM</td>
<td>-40 to 85</td>
<td>SJS</td>
<td>Samples</td>
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<td>-40 to 85</td>
<td>SJS</td>
<td>Samples</td>
</tr>
</tbody>
</table>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check [http://www.ti.com/productcontent](http://www.ti.com/productcontent) for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI’s terms “Lead-Free” or “Pb-Free” mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material).

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

*All dimensions are nominal*

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<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
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<th>SPQ</th>
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<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P1 (mm)</th>
<th>W (mm)</th>
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<td>4.0</td>
<td>8.0</td>
<td>Q1</td>
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### TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

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<td>250</td>
<td>182.0</td>
<td>182.0</td>
<td>20.0</td>
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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.
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